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April 1st, 2010 Renesas Electronics Corporation

Issued by: Renesas Electronics Corporation (http://www.renesas.com)
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MOS FIELD EFFECT TRANSISTOR NO100P

P-CHANNEL MOS FIELD EFFECT TRANSISTOR FOR SWITCHING

DESCRIPTION

The N0100P is a switching device, which can be driven directly by a 1.8 V power source.

This N0100P features a low on-state resistance and excellent switching characteristics, and is suitable for applications such as power switch of portable machine and so on.

FEATURES

- 1.8 V drive available
- Low on-state resistance

 $R_{DS(on)1} = 44 \text{ m}\Omega \text{ MAX}. \text{ (V}_{GS} = -4.5 \text{ V}, I_{D} = -2.0 \text{ A)}$

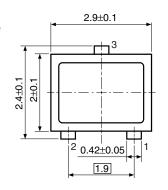
 $R_{DS(on)2} = 56 \text{ m}\Omega \text{ MAX.} \text{ (V}_{GS} = -3.0 \text{ V}, I_{D} = -2.0 \text{ A)}$

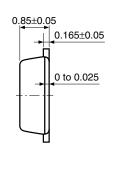
 $R_{DS(on)3} = 62 \text{ m}\Omega \text{ MAX}. \text{ (V}_{GS} = -2.5 \text{ V}, I_{D} = -2.0 \text{ A)}$

 $R_{DS(on)4} = 105 \text{ m}\Omega \text{ MAX}. \text{ (Vgs} = -1.8 \text{ V}, I_D = -1.5 \text{ A})$

Built-in gate protection diode

PACKAGE DRAWING (Unit: mm)





- 1: Source 2: Gate
- 2: Gate 3: Drain

ORDERING INFORMATION

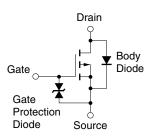
PART NUMBER	LEAD PLATING	PACKING	PACKAGE
N0100P-T1-AT	Pure Sn (Tin)	Tape 3000 p/reel	SOT-23F

Marking: XX

ABSOLUTE MAXIMUM RATINGS (TA = 25°C)

Drain to Source Voltage (V _{GS} = 0 V)	Voss	-12	V
Gate to Source Voltage (V _{DS} = 0 V)	Vgss	∓8.0	V
Drain Current (DC)	ID(DC)	∓3.5	Α
Drain Current (pulse) Note1	I _{D(pulse)}	∓12	Α
Total Power Dissipation	P _{T1}	0.2	W
Total Power Dissipation Note2	P _{T2}	1.3	W
Channel Temperature	Tch	150	°C
Storage Temperature	T_{stg}	-55 to +150	°C

EQUIVALENT CIRCUIT



- **Notes 1.** PW \leq 10 μ s, Duty Cycle \leq 1%
 - **2.** Mounted on FR-4 board of 50 mm \times 50 mm \times 1.6 mm, copper foil 100%, $t \le 5$ sec.

Remark The diode connected between the gate and source of the transistor serves as a protector against ESD. When this device actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.

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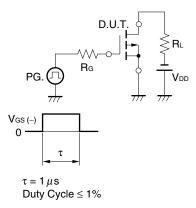


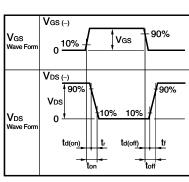
ELECTRICAL CHARACTERISTICS (TA = 25°C)

CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Zero Gate Voltage Drain Current	IDSS	V _{DS} = -12 V, V _{GS} = 0 V			-10	μΑ
Gate Leakage Current	Igss	V _{GS} = ∓8 V, V _{DS} = 0 V			∓10	μΑ
Gate to Source Cut-off Voltage	V _{GS(off)}	$V_{DS} = -10 \text{ V}, I_{D} = -1.0 \text{ mA}$	-0.45		-1.5	V
Forward Transfer Admittance ^{Note}	y _{fs}	$V_{DS} = -10 \text{ V}, I_{D} = -2.0 \text{ A}$	4			S
Drain to Source On-state Resistance ^{Note}	RDS(on)1	V _{GS} = -4.5 V, I _D = -2.0 A		37	44	mΩ
	RDS(on)2	V _{GS} = -3.0 V, I _D = -2.0 A		42	56	mΩ
	R _{DS(on)3}	V _{GS} = -2.5 V, I _D = -2.0 A		46	62	mΩ
	RDS(on)4	V _{GS} = -1.8 V, I _D = -1.5 A		60	105	mΩ
Input Capacitance	Ciss	V _{DS} = -10 V,		720		pF
Output Capacitance	Coss	V _{GS} = 0 V,		150		pF
Reverse Transfer Capacitance	Crss	f = 1.0 MHz		80		pF
Turn-on Delay Time	t _{d(on)}	$V_{DD} = -6 \text{ V}, I_D = -1.75 \text{ A},$		18		ns
Rise Time	tr	V _{GS} = -4.5 V,		37		ns
Turn-off Delay Time	t _{d(off)}	R _G = 10 Ω		240		ns
Fall Time	t _f			114		ns
Total Gate Charge	Q _G	$V_{DD} = -10 \text{ V},$		8.3		nC
Gate to Source Charge	Qgs	V _{GS} = -4.5 V,		1.3		nC
Gate to Drain Charge	Q _{GD}	I _D = -3.5 A		2.1		nC
Body Diode Forward Voltage ^{Note}	V _{F(S-D)}	I _F = 3.5 A, V _{GS} = 0 V		0.84		V
Reverse Recovery Time	Trr	I _F = 3.5 A, V _{GS} = 0 V,		270		ns
Reverse Recovery Charge	Qrr	di/dt = 50 A/μs		300		nC

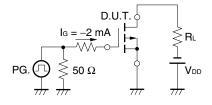
Note Pulsed

TEST CIRCUIT 1 SWITCHING TIME

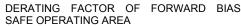


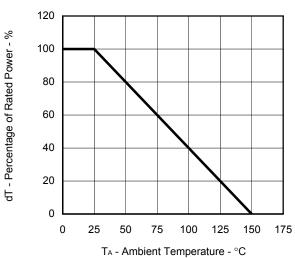


TEST CIRCUIT 2 GATE CHARGE

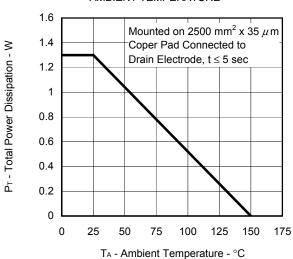


TYPICAL CHARACTERISTICS (TA = 25°C)

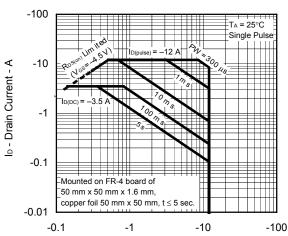




TOTAL POWER DISSIPATION vs. AMBIENT TEMPERATURE

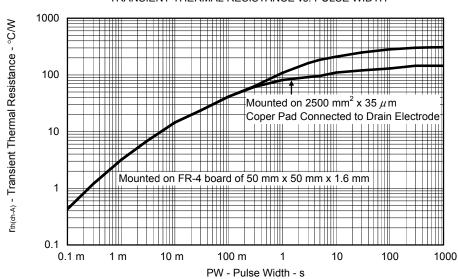


FORWARD BIAS SAFE OPERATING AREA



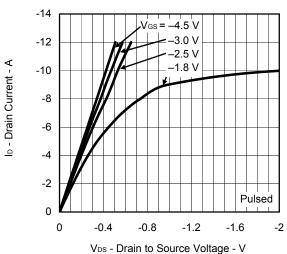
V_{DS} - Drain to Source Voltage - V

TRANSIENT THERMAL RESISTANCE vs. PULSE WIDTH

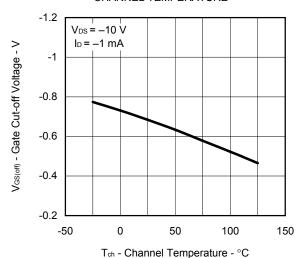


3

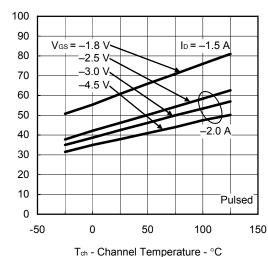
DRAIN CURRENT vs. DRAIN TO SOURCE VOLTAGE



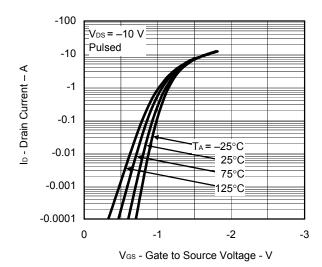
GATE CUT-OFF VOLTAGE vs. CHANNEL TEMPERATURE



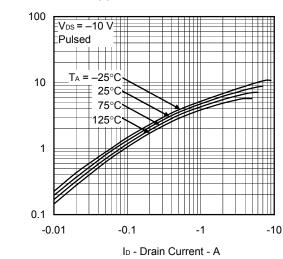
DRAIN TO SOURCE ON-STATE RESISTANCE vs. CHANNEL TEMPERATURE



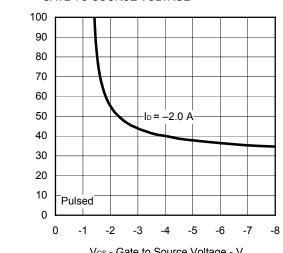
FORWARD TRANSFER CHARACTERISTICS



FORWARD TRANSFER ADMITTANCE vs. DRAIN CURRENT



DRAIN TO SOURCE ON-STATE RESISTANCE vs. GATE TO SOURCE VOLTAGE



R_{DS(m)} - Drain to Source On-state Resistance - mΩ

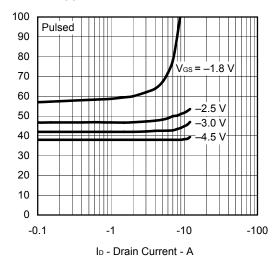
R_{DS(m)} - Drain to Source On-state Resistance - mΩ

| y_{fs} | - Forward Transfer Admittance - S

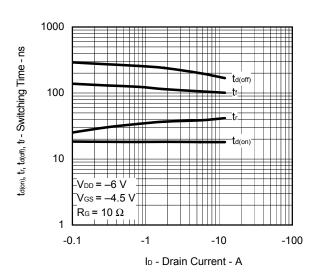


 $\mathsf{R}_{\mathsf{DS}(m)}$ - Drain to Source On-state Resistance - $m\Omega$

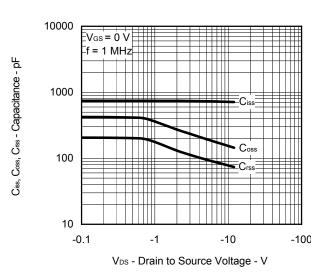
DRAIN TO SOURCE ON-STATE RESISTANCE vs. DRAIN CURRENT



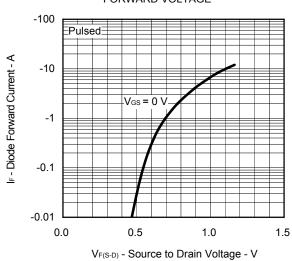
SWITCHING CHARACTERISTICS



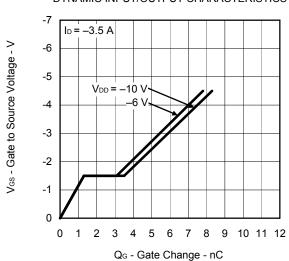
CAPACITANCE vs. DRAIN TO SOURCE VOLTAGE



SOURCE TO DRAIN DIODE FORWARD VOLTAGE



DYNAMIC INPUT/OUTPUT CHARACTERISTICS



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